











**SN74LVC1G139** 

SCES602E -AUGUST 2004-REVISED JANUARY 2018

# SN74LVC1G139 2-to-4 Line Decoder

#### **Features**

- Available in the Texas Instruments NanoStar<sup>™</sup> and NanoFree<sup>™</sup> Packages
- Supports 5-V V<sub>CC</sub> Operation
- Inputs Accept Voltages to 5.5 V
- Supports Down Translation to V<sub>CC</sub>
- Maximum t<sub>pd</sub> of 4.9 ns at 3.3 V and 15 pF
- Low Power Consumption, 10-µA Maximum I<sub>CC</sub>
- ±24-mA Output Drive at 3.3 V
- Ioff Supports Live Insertion, Partial-Power-Down Mode, and Back-Drive Protection
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- **ESD Protection Exceeds JESD22** 
  - 2000-V Human-Body Model (A114-A)
  - 200-V Machine Model (A115-A)
  - 1000-V Charged-Device Model (C101)

# 2 Applications

**AV Receivers** 

Solid State Drives (SSDs): Client and Enterprise

TVs: LCD, Digital, and High-Definition (HD)

Tablets: Enterprise Video Analytics: Server

## 3 Description

This SN74LVC1G139 2-to-4 line decoder is designed for 1.65-V to 5.5-V  $V_{CC}$  operation.

The SN74LVC1G139 2-line to 4-line decoder is designed to be used in high-performance memorydecoding or data-routing applications requiring very short propagation delay times. In high-performance memory systems, this decoder can be used to minimize the effects of system decoding. When used with high-speed memories using a fast enable circuit, the delay times of these decoders and the enable time of the memory usually are less than the typical access time of the memory. This means that the effective system delay introduced by the decoder is negligible.

NanoStar and NanoFree package technology is a major breakthrough in device packaging concepts, using the die as the package.

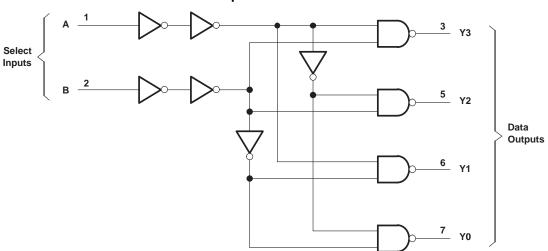
This device is fully specified for partial-power-down applications using  $I_{\text{off}}$  . The  $I_{\text{off}}$  circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

# Device Information<sup>(1)</sup>

| PART NUMBER     | PACKAGE   | BODY SIZE (NOM)   |
|-----------------|-----------|-------------------|
| SN74LVC1G139DCT | SM8 (8)   | 2.95 mm × 2.80 mm |
| SN74LVC1G139DCU | VSSOP (8) | 2.30 mm × 2.00 mm |
| SN74LVC1G139YZP | DSBGA (8) | 1.91 mm × 0.91 mm |

(1) For all available packages, see the orderable addendum at the end of the datasheet.

#### Simplified Schematic





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# 4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

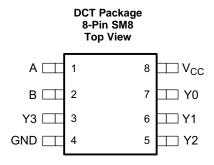
| Changes from Revision D (February 2014) to Revision E |   |      |  |  |  |
|---|---|------|--|--|--|
| •   | Updated the YZP package drawing   | 3    |  |  |  |
| Ch  | anges from Revision C (December 2005) to Revision D   | Page |  |  |  |
| •   | Added Applications section, Device Information table, ESD Ratings table, Thermal Information table, Typical Characteristics section, Feature Description section, Device Functional Modes, Application and Implementation section, Power Supply Recommendations section, Layout section, Device and Documentation Support section, and Mechanical, Packaging, and Orderable Information section |      |  |  |  |
| Ch  | anges from Revision B (December 2005) to Revision C   | Page |  |  |  |
| •   | Updated document to new TI data sheet format.   |      |  |  |  |
| •   | Updated Features.   | 1    |  |  |  |
| •   | Removed Ordering Information table  | 1    |  |  |  |

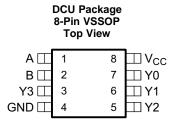
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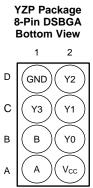
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# 5 Pin Configuration and Functions







#### **Pin Functions**

|                 | PIN      |     |     |  | 1/0 | DESCRIPTION |  |
|-----------------|----------|-----|-----|--|-----|-------------|--|
| NAME            | DCT, DCU | YZP | I/O | DESCRIPTION                                |     |             |  |
| Α               | 1        | A1  | I   | Adress input, bit 0                        |     |             |  |
| В               | 2        | B1  | 1   | Adress input, bit 1                        |     |             |  |
| Y <sub>3</sub>  | 3        | C1  | 0   | Output 3, low when B is high and A is high |     |             |  |
| GND             | 4        | D1  | _   | Ground                                     |     |             |  |
| Y <sub>2</sub>  | 5        | D2  | 0   | Output 2, low when B is high and A is low  |     |             |  |
| Y <sub>1</sub>  | 6        | C2  | 0   | Output 1, low when B is low and A is high  |     |             |  |
| Y <sub>0</sub>  | 7        | B2  | 0   | Output 0, low when B is low and A is low   |     |             |  |
| V <sub>CC</sub> | 8        | A2  | _   | Power pin                                  |     |             |  |



## 6 Specification

## 6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)<sup>(1)</sup>

|  |   | MIN                   | MAX | UNIT |
|--|---|-----------------------|-----|------|
| Supply Voltage, V <sub>CC</sub>                                    |   | -0.5                  | 6.5 | V    |
| Input Voltage, V <sub>I</sub>                                      |   | -0.5                  | 6.5 | V    |
| Voltage applied to any output in the high-impedance                | or power-off state, V <sub>O</sub> <sup>(2)</sup> | -0.5                  | 6.5 | V    |
| Voltage applied to any output in the high or low state             | -0.5  | V <sub>CC</sub> + 0.5 | V   |      |
| Input clamp current, I <sub>IK</sub>                               | V <sub>I</sub> < 0                                |                       | -50 | mA   |
| Output clamp current, I <sub>OK</sub>                              | V <sub>O</sub> < 0                                |                       | -50 | mA   |
| Continuous output current, I <sub>O</sub>                          |   |                       | ±50 | mA   |
| Continuous current through V <sub>CC</sub> or GND, I <sub>CC</sub> |   | ±100                  | mA  |      |
| Junction temperature, T <sub>J</sub>                               |   |                       | 150 | °C   |
| Storage temperature, T <sub>stg</sub>                              |   |                       | 150 | °C   |

<sup>(1)</sup> Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

## 6.2 ESD Ratings

|                    |                         |  | VALUE | UNIT |
|--------------------|-------------------------|--|-------|------|
|                    |                         | Human body model (HBM), per ANSI/ESDA/JEDEC JS-001 (1)                         | ±2500 |      |
| V <sub>(ESD)</sub> | Electrostatic discharge | Charged-device model (CDM), per JEDEC specification JESD22-C101 <sup>(2)</sup> | ±1500 | V    |
|                    |                         | Machine model  | ±200  |      |

<sup>(1)</sup> JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

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<sup>(2)</sup> The input and output negative-voltage ratings may be exceeded if the input and output current ratings are observed.

<sup>(3)</sup> The value of V<sub>CC</sub> is provided in the *Recommended Operating Conditions* table.



# 6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted) (1)

|                 |                                    |  | MIN                    | MAX                    | UNIT |  |
|-----------------|------------------------------------|--|------------------------|------------------------|------|--|
| .,              | Cumply walte as                    | Operating  | 1.65                   | 5.5                    | V    |  |
| V <sub>CC</sub> | Supply voltage                     | Data retention only  | 1.5                    |                        | V    |  |
|                 |                                    | V <sub>CC</sub> = 1.65 V to 1.95 V   | 0.65 × V <sub>CC</sub> |                        |      |  |
| .,              | I Park James Committee on          | V <sub>CC</sub> = 2.3 V to 2.7 V   | 1.7                    |                        | V    |  |
| $V_{IH}$        | High-level input voltage           | V <sub>CC</sub> = 3 V to 3.6 V   | 2                      |                        | V    |  |
|                 |                                    | V <sub>CC</sub> = 4.5 V to 5.5 V   | 0.7 × V <sub>CC</sub>  |                        |      |  |
|                 |                                    | V <sub>CC</sub> = 1.65 V to 1.95 V   |                        | 0.35 × V <sub>CC</sub> |      |  |
| .,              | Lave lavel Secret rights as        | V <sub>CC</sub> = 2.3 V to 2.7 V   |                        | 0.7                    | .,   |  |
| $V_{IL}$        | Low-level input voltage            | V <sub>CC</sub> = 3 V to 3.6 V   |                        | 0.8                    | V    |  |
|                 |                                    | V <sub>CC</sub> = 4.5 V to 5.5 V   |                        | $0.3 \times V_{CC}$    |      |  |
| VI              | Input voltage                      | •  | 0                      | 5.5                    | V    |  |
| Vo              | Output voltage                     |  | 0                      | V <sub>CC</sub>        | V    |  |
|                 |                                    | V <sub>CC</sub> = 1.65 V   |                        | -4                     |      |  |
|                 | High-level output current          | V <sub>CC</sub> = 2.3 V  |                        | -8                     |      |  |
| I <sub>OH</sub> |                                    | V 2V   |                        | -16                    | mA   |  |
|                 |                                    | $V_{CC} = 3 V$   |                        | -24                    |      |  |
|                 |                                    | V <sub>CC</sub> = 4.5 V  |                        | -32                    | 1    |  |
|                 |                                    | V <sub>CC</sub> = 1.65 V   | 4                      |                        |      |  |
|                 |                                    | V <sub>CC</sub> = 2.3 V  |                        | 8                      |      |  |
| $I_{OL}$        | Low-level output current           | V 2.V  |                        | 16                     | mA   |  |
|                 |                                    | V <sub>CC</sub> = 3 V  |                        | 24                     |      |  |
|                 |                                    | V <sub>CC</sub> = 4.5 V  |                        | 32                     |      |  |
|                 |                                    | $V_{CC} = 1.8 \text{ V} \pm 0.15 \text{ V}, 2.5 \text{ V} \pm 0.2 \text{ V}$ | 2 V 2                  |                        |      |  |
| Δt/Δν           | Input transition rise or fall rate | $V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$                                   |                        | 15                     | ns/V |  |
|                 |                                    | $V_{CC} = 5 \text{ V} \pm 0.5 \text{ V}$                                     |                        | 10                     |      |  |
| T <sub>A</sub>  | Operating free-air temperature     | <u>.</u>   | -40                    | 85                     | °C   |  |

<sup>(1)</sup> All unused inputs of the device must be held at V<sub>CC</sub> or GND to ensure proper device operation. See the *Implications of Slow or Floating CMOS Inputs* application report.

## 6.4 Thermal Information

|                      |  |           | SN74LVC1G139 |             |      |  |  |
|----------------------|--|-----------|--------------|-------------|------|--|--|
|                      | THERMAL METRIC <sup>(1)</sup>                | DCT (SM8) | DCU (VSSOP)  | YZP (DSBGA) | UNIT |  |  |
|                      |  | 8 PINS    | 8 PINS       | 8 PINS      |      |  |  |
| $R_{\theta JA}$      | Junction-to-ambient thermal resistance       | 194       | 195          | 106         | °C/W |  |  |
| $R_{\theta JC(top)}$ | Junction-to-case (top) thermal resistance    | 124       | 74           | 1.6         | °C/W |  |  |
| $R_{\theta JB}$      | Junction-to-board thermal resistance         | 106       | 74           | 11          | °C/W |  |  |
| ΨЈТ                  | Junction-to-top characterization parameter   | 48        | 6.7          | 3.1         | °C/W |  |  |
| ΨЈВ                  | Junction-to-board characterization parameter | 105       | 73           | 11          | °C/W |  |  |
| $R_{\theta JC(bot)}$ | Junction-to-case (bottom) thermal resistance | _         | _            | _           | °C/W |  |  |

For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report.



#### 6.5 Electrical Characteristics

over recommended operating free-air temperature range (unless otherwise noted)

| ı                | PARAMETER                   | TEST CONDITIONS  | MIN                   | TYP <sup>(1)</sup> | MAX  | UNIT                                  |  |
|------------------|-----------------------------|--|-----------------------|--------------------|------|---------------------------------------|--|
|                  |                             | $I_{OH} = -100 \mu A$ , $V_{CC} = 1.65 \text{ V}$ to 5.5 V                                       | V <sub>CC</sub> - 0.1 |                    |      |                                       |  |
|                  |                             | $I_{OH} = -4 \text{ mA}, V_{CC} = 1.65 \text{ V}$  | 1.2                   |                    |      |                                       |  |
|                  | High-level output           | $I_{OH} = -8 \text{ mA}, V_{CC} = 2.3 \text{ V}$   | 1.9                   |                    |      | V                                     |  |
| V <sub>OH</sub>  | voltage                     | $I_{OH} = -16 \text{ mA}, V_{CC} = 3 \text{ V}$  | 2.4                   |                    |      | V                                     |  |
|                  |                             | $I_{OH} = -24$ mA, $V_{CC} = 3$ V  | 2.3                   |                    |      |                                       |  |
|                  |                             | $I_{OH} = -32 \text{ mA}, V_{CC} = 4.5 \text{ V}$  | 3.8                   |                    |      |                                       |  |
|                  |                             | $I_{OL} = 100 \mu A$ , $V_{CC} = 1.65 V$ to 5.5 V  |                       |                    | 0.1  |                                       |  |
|                  |                             | I <sub>OL</sub> = 4 mA, V <sub>CC</sub> = 1.65 V   |                       |                    | 0.45 |                                       |  |
| .,               | Low-level output<br>voltage | $I_{OL} = 8 \text{ mA}, V_{CC} = 2.3 \text{ V}$  |                       |                    | 0.3  | \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ |  |
| V <sub>OL</sub>  |                             | $I_{OL}$ = 16 mA, $V_{CC}$ = 3 V   |                       |                    | 0.4  | V                                     |  |
|                  |                             | $I_{OL}$ = 24 mA, $V_{CC}$ = 3 V   |                       |                    | 0.55 | ·                                     |  |
|                  |                             | $I_{OL} = 32 \text{ mA}, V_{CC} = 4.5 \text{ V}$   |                       |                    | 0.55 |                                       |  |
| II               | Inflection-point current    | A or B inputs:<br>$V_1 = 5.5 \text{ V or GND}, V_{CC} = 0 \text{ to } 5.5 \text{ V}$             |                       |                    | ±1   | μΑ                                    |  |
| I <sub>off</sub> | Off-state current           | $V_{I}$ or $V_{O} = 5.5 \text{ V}, V_{CC} = 0$   |                       |                    | ±5   | μΑ                                    |  |
| $I_{CC}$         | Supply current              | $V_I = 5.5 \text{ V or GND}, I_O = 0, V_{CC} = 1.65 \text{ V to } 5.5 \text{ V}$                 |                       |                    | 10   | μΑ                                    |  |
| $\Delta I_{CC}$  | Supply current change       | One input at $V_{CC} - 0.6 \text{ V}$ , other inputs at $V_{CC}$ or GND, $V_{CC}$ = 3 V to 5.5 V |                       |                    | 500  | μΑ                                    |  |
| Ci               | Input capacitance           | $V_I = V_{CC}$ or GND, $V_{CC} = 3.3 \text{ V}$  |                       | 4                  |      | pF                                    |  |

<sup>(1)</sup> All typical values are at  $V_{CC}$  = 3.3 V,  $T_A$  = 25°C.

## 6.6 Switching Characteristics

over recommended operating free-air temperature range,  $C_L$  = 15 pF (unless otherwise noted)

|                 | PARAMETER   |             | TEST CONDITIONS |   |                            | MAX  | UNIT |
|-----------------|-------------|-------------|-----------------|---|----------------------------|------|------|
|                 |             |             |                 | $V_{CC} = 1.8 \text{ V} \pm 0.15 \text{ V}$ | 2.7                        | 15.3 |      |
|                 |             |             | See Table 2     | $V_{CC} = 2.5 \text{ V} \pm 0.2 \text{ V}$  | 1.5                        | 7.5  |      |
|                 |             | A or B-to-Y | See Table 2     | $V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$  | CC = 3.3 V ± 0.3 V 0.9 4.9 |      |      |
|                 | Propagation |             |                 | $V_{CC} = 5 V \pm 0.5 V$                    | 0.8                        | 3.6  | ns   |
| t <sub>pd</sub> | delay time  | A OI D-10-1 |                 | $V_{CC} = 1.8 \text{ V} \pm 0.15 \text{ V}$ | 3                          | 16.7 |      |
|                 |             |             | Con Toble 2     | $V_{CC} = 2.5 \text{ V} \pm 0.2 \text{ V}$  | 1.6                        | 8.2  |      |
|                 |             |             | See Table 3     | $V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$  | 1.2                        | 5.9  |      |
|                 |             |             |                 | $V_{CC} = 5 \text{ V} \pm 0.5 \text{ V}$    | 1.1                        | 4.2  |      |

# 6.7 Operating Characteristics

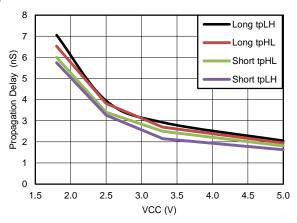
 $T_A = 25^{\circ}C$ 

|                                | PARAMETER         |            | TEST<br>CONDITIONS      | MIN | TYP | MAX | UNIT |
|--------------------------------|-------------------|------------|-------------------------|-----|-----|-----|------|
|                                |                   |            | V <sub>CC</sub> = 1.8 V |     | 31  |     |      |
| <b>c</b> (1)                   | Power dissipation | f 10 MHz   | V <sub>CC</sub> = 2.5 V |     | 34  |     | ~F   |
| C <sub>pd</sub> <sup>(1)</sup> | capacitance       | f = 10 MHz | V <sub>CC</sub> = 3.3 V |     | 36  |     | pF   |
|                                |                   |            | V <sub>CC</sub> = 5 V   |     | 39  |     |      |

(1) Two outputs switching.



# 7 Typical Characteristics



(1) Short is 2 inverter path. Long is 3 inverter path.

Figure 1. Propagation Delay vs VCC

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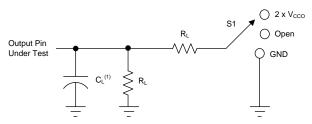
#### 8 Parameter Measurement Information

Unless otherwise noted, all input pulses are supplied by generators that have the following characteristics:

- PRR ≤ 10 MHz
- $Z_{\rm O} = 50~\Omega$

#### **NOTE**

All parameters and waveforms are not applicable to all devices.



(1) C<sub>L</sub> includes probe and jig capacitance.

Figure 2. Load Circuit

**Table 1. Loading Conditions for Parameter** 

| TEST  | <b>S</b> 1 |
|---|------------|
| t <sub>PLH</sub> <sup>(1)</sup> , t <sub>PHL</sub> <sup>(1)</sup> | Open       |
| $t_{PLZ}^{(2)},t_{PZL}^{(3)}$                                     | $V_{LOAD}$ |
| t <sub>PHZ</sub> <sup>(2)</sup> , t <sub>PZH</sub> <sup>(3)</sup> | GND        |

- (1)  $t_{PLH}$  and  $t_{PHL}$  are the same as  $t_{pd}$ .
- (2) t<sub>PLZ</sub> and t<sub>PHZ</sub> are the same as t<sub>dis</sub>.
   (3) t<sub>PZL</sub> and t<sub>PZH</sub> are the same as t<sub>en</sub>.

Table 2. Loading Conditions for V<sub>CC</sub> – Case 1

| V               | INP             | UTS                            | V                   | V                   |                | В              | V            |  |
|-----------------|-----------------|--------------------------------|---------------------|---------------------|----------------|----------------|--------------|--|
| V <sub>CC</sub> | VI              | t <sub>r</sub> /t <sub>f</sub> | V <sub>M</sub>      | V <sub>LOAD</sub>   | C <sub>L</sub> | R <sub>L</sub> | $V_{\Delta}$ |  |
| 1.8 V ± 0.15 V  | V <sub>CC</sub> | ≤ 2 ns                         | V <sub>CC</sub> / 2 | 2 × V <sub>CC</sub> | 15 pF          | 1 ΜΩ           | 0.15 V       |  |
| 2.5 V ± 0.2 V   | V <sub>CC</sub> | ≤ 2 ns                         | V <sub>CC</sub> / 2 | 2 × V <sub>CC</sub> | 15 pF          | 1 ΜΩ           | 0.15 V       |  |
| 3.3 V ± 0.3 V   | 3 V             | ≤ 2.5 ns                       | 1.5 V               | 6 V                 | 15 pF          | 1 ΜΩ           | 0.3 V        |  |
| 5 V ± 0.5 V     | V <sub>CC</sub> | ≤ 2.5 ns                       | V <sub>CC</sub> / 2 | 2 × V <sub>CC</sub> | 15 pF          | 1 ΜΩ           | 0.3 V        |  |

Table 3. Loading Conditions for  $V_{\text{CC}}$  – Case 2

| V               | INP      | UTS                            | V                   | V                   | C     | В      | V            |  |
|-----------------|----------|--------------------------------|---------------------|---------------------|-------|--------|--------------|--|
| V <sub>CC</sub> | $V_{l}$  | t <sub>r</sub> /t <sub>f</sub> | V <sub>M</sub>      | V <sub>LOAD</sub>   | CL    | $R_L$  | $V_{\Delta}$ |  |
| 1.8 V ± 0.15 V  | $V_{CC}$ | ≤ 2 ns                         | V <sub>CC</sub> / 2 | 2 × V <sub>CC</sub> | 30 pF | 1 ΜΩ   | 0.15 V       |  |
| 2.5 V ± 0.2 V   | $V_{CC}$ | ≤ 2 ns                         | V <sub>CC</sub> / 2 | 2 × V <sub>CC</sub> | 30 pF | 500 MΩ | 0.15 V       |  |
| 3.3 V ± 0.3 V   | 3 V      | ≤ 2.5 ns                       | 1.5 V               | 6 V                 | 30 pF | 500 MΩ | 0.3 V        |  |
| 5 V ± 0.5 V     | $V_{CC}$ | ≤ 2.5 ns                       | V <sub>CC</sub> / 2 | 2 × V <sub>CC</sub> | 30 pF | 500 MΩ | 0.3 V        |  |



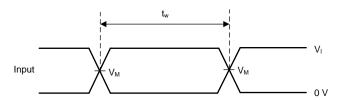
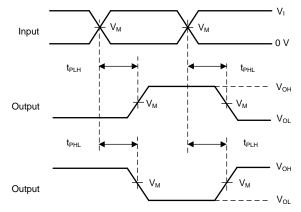


Figure 3. Voltage Waveforms: Pulse Duration



(1) The outputs are measured one at a time, with one transition per measurement.

Figure 4. Voltage Waveforms: Propagation Delay Times Inverting And Noninverting Outputs

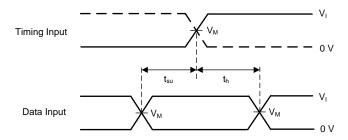
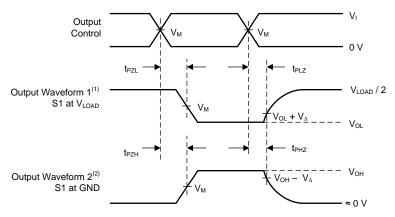


Figure 5. Voltage Waveforms: Setup and Hold Times



- (1) Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control.
- (2) Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- (3) The outputs are measured one at a time, with one transition per measurement.

Figure 6. Voltage Waveforms: Enable and Disable Times, Low- and High-Level Enabling

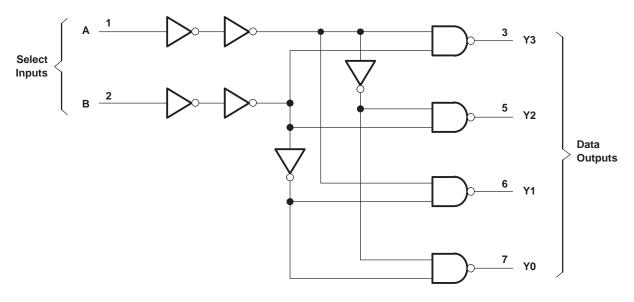


## 9 Detailed Description

#### 9.1 Overview

The LVC1G139 device decodes the 2-bit input to one of the four outputs. The B input is the most significant bit and the Y outputs are active low. The propagation delays are very short and well matched (see Figure 1). Supply voltage from 1.65-V to 5.5-V is supported.

## 9.2 Functional Block Diagram



## 9.3 Feature Description

NanoStar and NanoFree package technology is a major breakthrough in device packaging concepts, using the die as the package.

This device is fully specified for partial-power-down applications using  $I_{off}$ . The  $I_{off}$  circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

#### 9.4 Device Functional Modes

Table 4 lists the functional modes of the SN74LVC1G139 device.

**Table 4. Function Table** 

| INP | UTS |                | OUTPUTS        |                |                |  |  |  |  |
|-----|-----|----------------|----------------|----------------|----------------|--|--|--|--|
| В   | Α   | Y <sub>0</sub> | Y <sub>1</sub> | Y <sub>2</sub> | Y <sub>3</sub> |  |  |  |  |
| L   | L   | L              | Н              | Н              | Н              |  |  |  |  |
| L   | Н   | Н              | L              | Н              | Н              |  |  |  |  |
| Н   | L   | Н              | Н              | L              | Н              |  |  |  |  |
| Н   | Н   | Н              | Н              | Н              | L              |  |  |  |  |

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# 10 Application and Implementation

#### NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

## 10.1 Application Information

The SN74LVC1G139 device is a 2-of-4 decoder and demultiplexer. This device decodes the 2-bit address on inputs A (bit 0) and B (bit 1) then provides a logic low on the matching address output. It can produce 24 mA of drive current at 3.3 V, making it ideal for driving multiple outputs.

## 10.2 Typical Application

This is an address line decoder using a 16-bit bus example; address bus lines 14 and 15 are decoded and drive four active low chip selects. Each output covers 16K address space mapped by the address bus lines 0 through 13

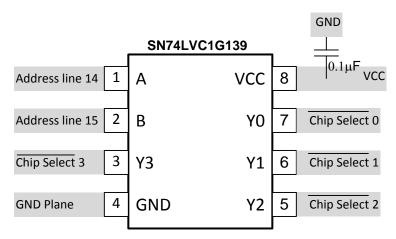


Figure 7. Typical Application Diagram

## 10.2.1 Design Requirements

This device uses CMOS technology and has balanced output drive. Take care to avoid bus contention because it can drive currents that would exceed maximum limits. Outputs can be combined to produce higher drive but the high drive will also create faster edges into light loads so routing and load conditions should be considered to prevent ringing.

#### 10.2.2 Detailed Design Procedure

- 1. Recommended Input Conditions:
  - Rise time and fall time specifications ( $\Delta t/\Delta V$ ) are shown in the Recommended Operating Conditions table.
  - Specified high (V<sub>IH</sub>) and low voltage (V<sub>IL</sub>) levels are shown in the Recommended Operating Conditions
    table.
  - Inputs are overvoltage tolerant allowing them to go as high as 5.5 V at any valid  $V_{CC}$ .
- 2. Recommend Output Conditions:
  - Load currents should not exceed 50 mA per output and 100 mA total for the part.
  - Series resistors on the output may be used if the user desires to slow the output edge signal or limit the output current.



## **Typical Application (continued)**

#### 10.2.3 Application Curve

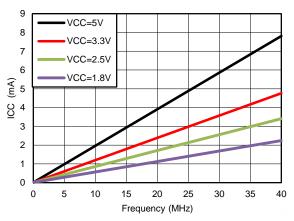


Figure 8. I<sub>CC</sub> vs Frequency Load is 15 pF

# 11 Power Supply Recommendations

The power supply can be any voltage between the minimum and maximum supply voltage rating located in the *Recommended Operating Conditions* table.

Each  $V_{CC}$  terminal should have a good bypass capacitor to prevent power disturbance. For devices with a single supply, a 0.1- $\mu F$  capacitor is recommended. If there are multiple  $V_{CC}$  terminals, then 0.01- $\mu F$  or 0.022- $\mu F$  capacitors are recommended for each power terminal. Parallel multiple bypass capacitors are allowed to reject different frequencies of noise. Multiple bypass capacitors may be paralleled to reject different frequencies of noise. The bypass capacitor must be installed as close to the power terminal as possible for the best results.

#### 12 Layout

#### 12.1 Layout Guidelines

When using multiple bit logic devices, inputs should not float. In many cases, functions or parts of functions of digital logic devices are unused. Some examples are when only two inputs of a triple-input AND gate are used, or when only 3 of the 4-buffer gates are used. Such input pins should not be left unconnected because the undefined voltages at the outside connections result in undefined operational states.

Specified in Figure 9 are rules that must be observed under all circumstances. All unused inputs of digital logic devices must be connected to a high or low bias to prevent them from floating. The logic level that should be applied to any particular unused input depends on the function of the device. Generally they will be tied to GND or V<sub>CC</sub>, whichever makes more sense or is more convenient.

#### 12.2 Layout Example



Figure 9. Layout Diagram



## 13 Device and Documentation Support

## 13.1 Documentation Support

#### 13.1.1 Related Documentation

For related documentation, see the following:

Texas Instruments, Implications of Slow or Floating CMOS Inputs application report

#### 13.2 Community Resources

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of

TI E2E™ Online Community TI's Engineer-to-Engineer (E2E) Community. Created to foster collaboration among engineers. At e2e.ti.com, you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

Design Support TI's Design Support Quickly find helpful E2E forums along with design support tools and contact information for technical support.

#### 13.3 Trademarks

NanoStar, NanoFree, E2E are trademarks of Texas Instruments. All other trademarks are the property of their respective owners.

#### 13.4 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

#### 13.5 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.

## Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.





29-Jan-2021

#### PACKAGING INFORMATION

| Orderable Device | Status (1) | Package Type | Package<br>Drawing | Pins | Package<br>Qty | Eco Plan     | Lead finish/<br>Ball material | MSL Peak Temp      | Op Temp (°C) | Device Marking (4/5) | Samples |
|------------------|------------|--------------|--------------------|------|----------------|--------------|-------------------------------|--------------------|--------------|----------------------|---------|
| 74LVC1G139DCTRE4 | ACTIVE     | SM8          | DCT                | 8    | 3000           | RoHS & Green | NIPDAU                        | Level-1-260C-UNLIM | -40 to 85    | C39<br>(R, Z)        | Samples |
| 74LVC1G139DCUTG4 | ACTIVE     | VSSOP        | DCU                | 8    | 250            | RoHS & Green | NIPDAU                        | Level-1-260C-UNLIM | -40 to 85    | C39R                 | Samples |
| SN74LVC1G139DCTR | ACTIVE     | SM8          | DCT                | 8    | 3000           | RoHS & Green | NIPDAU                        | Level-1-260C-UNLIM | -40 to 85    | C39<br>(R, Z)        | Samples |
| SN74LVC1G139DCTT | ACTIVE     | SM8          | DCT                | 8    | 250            | RoHS & Green | NIPDAU                        | Level-1-260C-UNLIM | -40 to 85    | C39<br>(R, Z)        | Samples |
| SN74LVC1G139DCUR | ACTIVE     | VSSOP        | DCU                | 8    | 3000           | RoHS & Green | NIPDAU   SN                   | Level-1-260C-UNLIM | -40 to 85    | (C39J, C39Q, C39R)   | Samples |
| SN74LVC1G139DCUT | ACTIVE     | VSSOP        | DCU                | 8    | 250            | RoHS & Green | NIPDAU   SN                   | Level-1-260C-UNLIM | -40 to 85    | (C39J, C39Q, C39R)   | Samples |
| SN74LVC1G139YZPR | ACTIVE     | DSBGA        | YZP                | 8    | 3000           | RoHS & Green | SNAGCU                        | Level-1-260C-UNLIM | -40 to 85    | DFN                  | Samples |

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

**Green:** TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

<sup>(3)</sup> MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

<sup>(4)</sup> There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

<sup>(5)</sup> Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.



# **PACKAGE OPTION ADDENDUM**

29-Jan-2021

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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# **PACKAGE MATERIALS INFORMATION**

www.ti.com 23-Oct-2020

# TAPE AND REEL INFORMATION





|    | Dimension designed to accommodate the component width     |
|----|---|
|    | Dimension designed to accommodate the component length    |
| K0 | Dimension designed to accommodate the component thickness |
| W  | Overall width of the carrier tape                         |
| P1 | Pitch between successive cavity centers                   |

## QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



#### \*All dimensions are nominal

| Device           | Package<br>Type | Package<br>Drawing | Pins | SPQ  | Reel<br>Diameter<br>(mm) | Reel<br>Width<br>W1 (mm) | A0<br>(mm) | B0<br>(mm) | K0<br>(mm) | P1<br>(mm) | W<br>(mm) | Pin1<br>Quadrant |
|------------------|-----------------|--------------------|------|------|--------------------------|--------------------------|------------|------------|------------|------------|-----------|------------------|
| 74LVC1G139DCUTG4 | VSSOP           | DCU                | 8    | 250  | 180.0                    | 8.4                      | 2.25       | 3.35       | 1.05       | 4.0        | 8.0       | Q3               |
| SN74LVC1G139DCTR | SM8             | DCT                | 8    | 3000 | 180.0                    | 13.0                     | 3.35       | 4.5        | 1.55       | 4.0        | 12.0      | Q3               |
| SN74LVC1G139DCTT | SM8             | DCT                | 8    | 250  | 180.0                    | 13.0                     | 3.35       | 4.5        | 1.55       | 4.0        | 12.0      | Q3               |
| SN74LVC1G139DCUR | VSSOP           | DCU                | 8    | 3000 | 178.0                    | 9.5                      | 2.25       | 3.35       | 1.05       | 4.0        | 8.0       | Q3               |
| SN74LVC1G139DCUR | VSSOP           | DCU                | 8    | 3000 | 180.0                    | 8.4                      | 2.25       | 3.35       | 1.05       | 4.0        | 8.0       | Q3               |
| SN74LVC1G139DCUR | VSSOP           | DCU                | 8    | 3000 | 178.0                    | 9.0                      | 2.25       | 3.35       | 1.05       | 4.0        | 8.0       | Q3               |
| SN74LVC1G139DCUT | VSSOP           | DCU                | 8    | 250  | 178.0                    | 9.5                      | 2.25       | 3.35       | 1.05       | 4.0        | 8.0       | Q3               |
| SN74LVC1G139DCUT | VSSOP           | DCU                | 8    | 250  | 178.0                    | 9.0                      | 2.25       | 3.35       | 1.05       | 4.0        | 8.0       | Q3               |
| SN74LVC1G139YZPR | DSBGA           | YZP                | 8    | 3000 | 178.0                    | 9.2                      | 1.02       | 2.02       | 0.63       | 4.0        | 8.0       | Q1               |

www.ti.com 23-Oct-2020



\*All dimensions are nominal

| Device           | Package Type | Package Drawing | Pins | SPQ  | Length (mm) | Width (mm) | Height (mm) |
|------------------|--------------|-----------------|------|------|-------------|------------|-------------|
| 74LVC1G139DCUTG4 | VSSOP        | DCU             | 8    | 250  | 202.0       | 201.0      | 28.0        |
| SN74LVC1G139DCTR | SM8          | DCT             | 8    | 3000 | 182.0       | 182.0      | 20.0        |
| SN74LVC1G139DCTT | SM8          | DCT             | 8    | 250  | 182.0       | 182.0      | 20.0        |
| SN74LVC1G139DCUR | VSSOP        | DCU             | 8    | 3000 | 202.0       | 201.0      | 28.0        |
| SN74LVC1G139DCUR | VSSOP        | DCU             | 8    | 3000 | 202.0       | 201.0      | 28.0        |
| SN74LVC1G139DCUR | VSSOP        | DCU             | 8    | 3000 | 180.0       | 180.0      | 18.0        |
| SN74LVC1G139DCUT | VSSOP        | DCU             | 8    | 250  | 202.0       | 201.0      | 28.0        |
| SN74LVC1G139DCUT | VSSOP        | DCU             | 8    | 250  | 180.0       | 180.0      | 18.0        |
| SN74LVC1G139YZPR | DSBGA        | YZP             | 8    | 3000 | 220.0       | 220.0      | 35.0        |





#### NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
  4. Reference JEDEC registration MO-187 variation CA.





NOTES: (continued)

- 5. Publication IPC-7351 may have alternate designs.
- 6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.





NOTES: (continued)

- 7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 8. Board assembly site may have different recommendations for stencil design.







#### NOTES:

- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.





NOTES: (continued)

5. Publication IPC-7351 may have alternate designs.6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.





NOTES: (continued)

- 7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 8. Board assembly site may have different recommendations for stencil design.





DIE SIZE BALL GRID ARRAY



#### NOTES:

- All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.



DIE SIZE BALL GRID ARRAY



NOTES: (continued)

3. Final dimensions may vary due to manufacturing tolerance considerations and also routing constraints. For more information, see Texas Instruments literature number SNVA009 (www.ti.com/lit/snva009).



DIE SIZE BALL GRID ARRAY



NOTES: (continued)

4. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release.



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